2SB1156

Silicon PNP epitaxial planar type

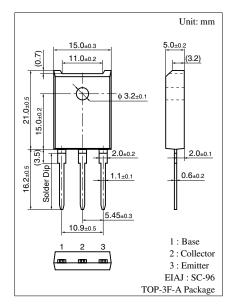
For power switching Complementary to 2SD1707

Features

- \bullet Low collector to emitter saturation voltage $V_{CE(sat)}$
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- \bullet Large collector current I_{C}
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Hatings $T_{C} = 25 C$								
Parameter		Symbol	Rating	Unit				
Collector to base voltage		V _{CBO}	-130	V				
Collector to emitter voltage		V _{CEO}	-80	V				
Emitter to base voltage		V _{EBO}	-7	V				
Peak collector current		I _{CP}	-30	А				
Collector current		I _C	-20	А				
Collector power	$T_C = 25^{\circ}C$	P _C	100	W				
dissipation	$T_a = 25^{\circ}C$		3					
Junction temperature		Tj	150	°C				
Storage temperature		T _{stg}	-55 to +150	°C				

Absolute Maximum Ratings $T_C = 25^{\circ}C$



Electrical Characteristics $T_C = 25^{\circ}C$

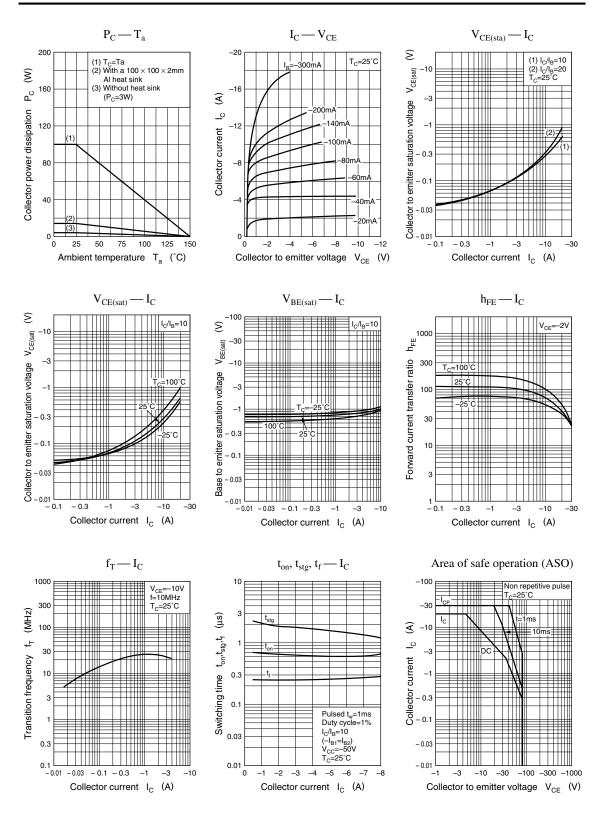
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = -100 \text{ V}, I_E = 0$			-10	μΑ
Emitter cutoff current	I _{EBO}	$V_{EB} = -5 V, I_C = 0$			-50	μΑ
Collector to emitter voltage	V _{CEO}	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = 0$	-80			V
Forward current transfer ratio	h _{FE1}	$V_{CE} = -2 V, I_C = -0.1 A$	45			
	h _{FE2} *	$V_{CE} = -2 V, I_C = -3 A$	90		260	
	h _{FE3}	$V_{CE} = -2 V, I_C = -10 A$	30			
Collector to emitter saturation voltage	V _{CE(sat)1}	$I_{\rm C} = -8$ A, $I_{\rm B} = -0.4$ A			- 0.5	V
	V _{CE(sat)2}	$I_{\rm C} = -20 \text{ A}, I_{\rm B} = -2 \text{ A}$			-1.5	V
Base to emitter saturation voltage	V _{BE(sat)1}	$I_{\rm C} = -8$ A, $I_{\rm B} = -0.4$ A			-1.5	V
	V _{BE(sat)2}	$I_{\rm C} = -20 \text{ A}, I_{\rm B} = -2 \text{ A}$			-2.5	V
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 10 \text{ MHz}$		25		MHz
Turn-on time	t _{on}	$I_{C} = -3 \text{ A}, I_{B1} = -0.8 \text{ A}, I_{B2} = 0.8 \text{ A},$		0.5		μs
Storage time	t _{stg}	$V_{\rm CC} = -50 \text{ V}$		1.2		μs
Fall time	t _f			0.2		μs

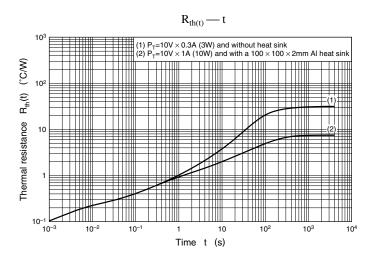
Note) *: Rank classification

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Rank	Q	Р		
h _{FE2}	90 to 180	130 to 260		

Ordering can be made by the common rank (PQ rank $h_{FE2} = 90$ to 260) in the rank classification.





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